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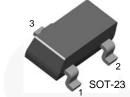


August 2015

BC846 / BC847 / BC848 / BC850 NPN Epitaxial Silicon Transistor

Features

- Switching and Amplifier Applications
- · Suitable for Automatic Insertion in Thick and Thin-film Circuits
- Low Noise: BC850
- Complement to BC856, BC857, BC858, BC859, and BC860



1. Base 2. Emitter 3. Collector

Ordering Information(1)

Part Number	Marking	Package	Packing Method
BC846AMTF	8AA	SOT-23 3L	Tape and Reel
BC846BMTF	8AB	SOT-23 3L	Tape and Reel
BC846CMTF	8AC	SOT-23 3L	Tape and Reel
BC847AMTF	8BA	SOT-23 3L	Tape and Reel
BC847BMTF	8BB	SOT-23 3L	Tape and Reel
BC847CMTF	8BC	SOT-23 3L	Tape and Reel
BC848BMTF	8CB	SOT-23 3L	Tape and Reel
BC848CMTF	8CC	SOT-23 3L	Tape and Reel
BC850AMTF	8EA	SOT-23 3L	Tape and Reel
BC850CMTF	8EC	SOT-23 3L	Tape and Reel

Note:

1. Affix "-A,-B,-C" means h_{FE} classification. Affix "-M" means SOT-23 package. Affix "-TF" means the tape and reel type packing.

1

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parame	Value	Unit		
		BC846	80	V	
V_{CBO}	Collector-Base Voltage	BC847 / BC850	50		
		BC848	30		
		BC846	65		
V_{CEO}	Collector-Emitter Voltage	BC847 / BC850	45	V	
		BC848	30		
V	Emitter-Base Voltage	BC846 / BC847	6	V	
V_{EBO}		BC848 / BC850	5		
I _C	Collector Current (DC)		100	mA	
TJ	Junction Temperature		150	°C	
T _{STG}	Storage Temperature Range		-65 to +150	°C	

Thermal Characteristics(2)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter	Value	Unit
D	Power Dissipation	310	mW
P _D	Derate Above 25°C	2.48	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	403	°C/W

Note:

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics(3)

Values are at $T_A = 25$ °C unless otherwise noted.

Symbol	Parameter		Conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector Cut-Off Current		$V_{CB} = 30 \text{ V}, I_{E} = 0$			15	nA
h _{FE}	DC Current Gain		$V_{CE} = 5 \text{ V}, I_{C} = 2 \text{ mA}$	110		800	
V _{CE} (sat)	.)		$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$		90	250	mV
vCE(sat)			$I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$		200	600	1110
\/(eat)	V _{BE} (sat) Collector-Base Saturation Voltage		$I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$		700		mV
v _{BE} (sat)			$I_C = 100 \text{ mA}, I_B = 5 \text{ mA}$		900		IIIV
V (on) Rose Em		nitter On Voltage	$V_{CE} = 5 \text{ V}, I_{C} = 2 \text{ mA}$	580	660	700	mV
V _{BE} (on)	Base-Emitter On Voltage		$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$			720	IIIV
f _T			$V_{CE} = 5 \text{ V, } I_{C} = 10 \text{ mA,}$ f = 100 MHz		300		MHz
C _{ob}	Output Capacitance		$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		3.5	6.0	pF
C _{ib}	Input Capacitance		$V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1 \text{ MHz}$		9		pF
	Noise Figure	BC846 / BC847 / BC848	$V_{CE} = 5 \text{ V, } I_{C} = 200 \mu\text{A,}$ $R_{G} = 2 k\Omega, f = 1 k\text{Hz}$		2.0	10.0	dB
NF		BC850			1.2	4.0	
		BC850	$V_{CE} = 5 \text{ V}, I_{C} = 200 \mu\text{A}, R_{G} = 2 \text{ k}\Omega, f = 30 \text{ to } 15000 \text{ Hz}$		1.4	3.0	

Note:

3. Pulse test: pulse width $\leq 300~\mu s,$ duty cycle $\leq 2\%$

h_{FE} Classification

Classification	Α	В	С
h _{FE}	110 ~ 220	200 ~ 450	420 ~ 800

Typical Performance Characteristics

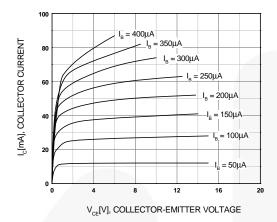


Figure 1. Static Characteristic

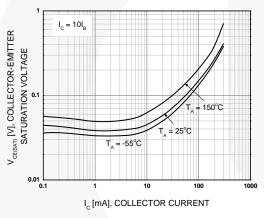


Figure 3. Currector-Emitter Saturation Voltage

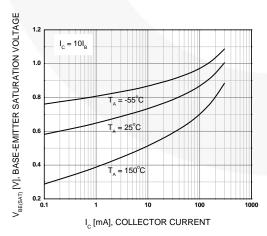


Figure 5. Base-Emitter Saturation Voltage

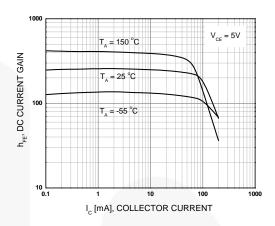


Figure 2. DC Current Gain

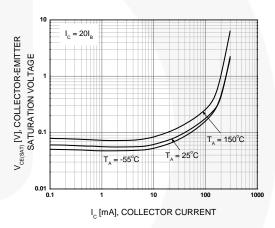


Figure 4. Currector-Emitter Saturation Voltage

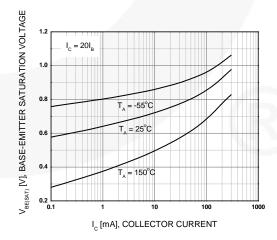


Figure 6. Base-Emitter Saturation Voltage

Typical Performance Characteristics (Continued)

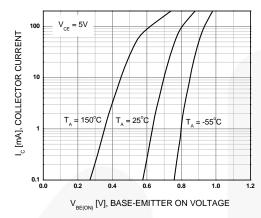


Figure 7. Base-Emitter On Voltage

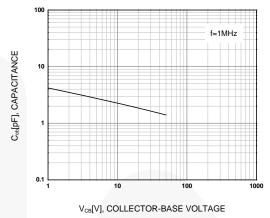


Figure 8. Collector Output Capacitance

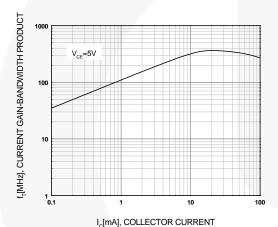
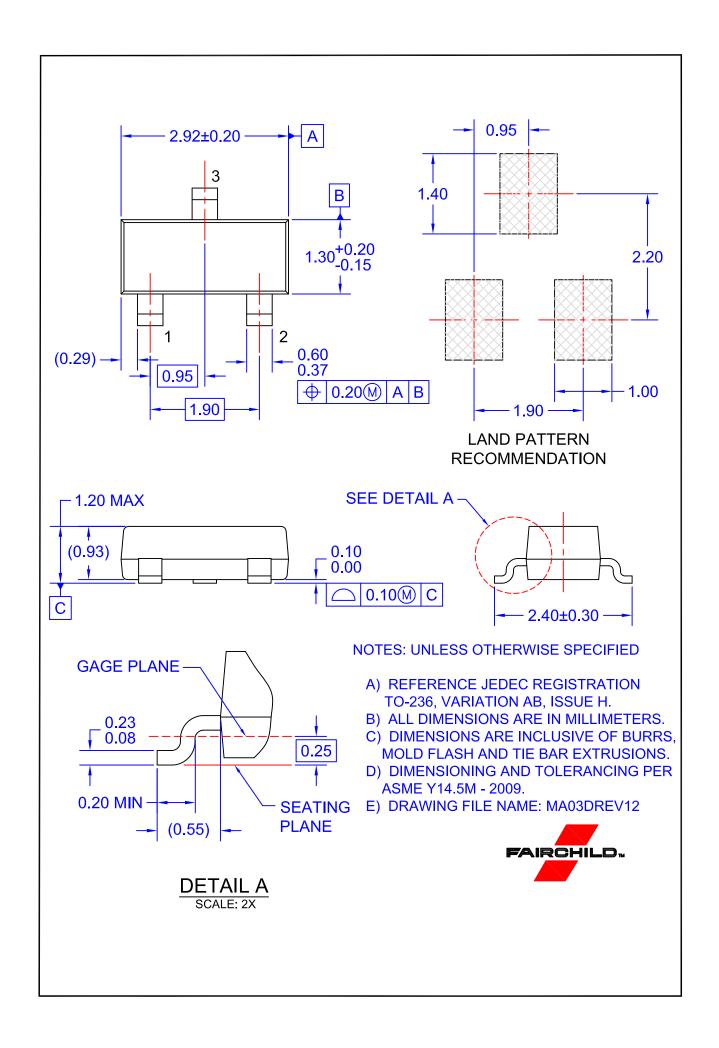


Figure 9. Current Gain Bandwidth Product



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